

### SMA/DO-214AC

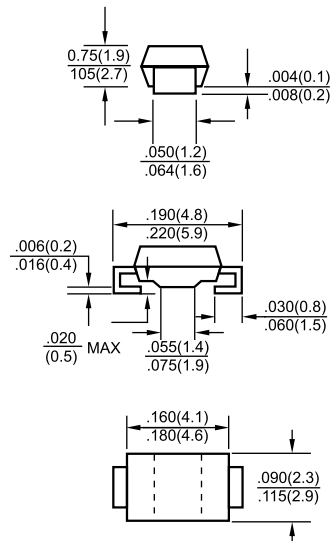


### Features

- ✦ Glass passivated junction chip
- ✦ For surface mounted application
- ✦ Low profile package
- ✦ Built-in strain relief
- ✦ Ideal for automated placement
- ✦ Easy pick and place
- ✦ Superfast recovery time for high efficiency
- ✦ Glass passivated chip junction
- ✦ High temperature soldering:  
260°C/10 seconds at terminals
- ✦ Plastic material used carries Underwriters  
Laboratory Classification 94V-0

### Mechanical Data

- ✦ Cases: Molded plastic
- ✦ Terminals: Pure tin plated, lead free.
- ✦ Polarity: Indicated by cathode band
- ✦ Packing: 12mm tape
- ✦ Weight: 0.064 gram



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	ES 2AA	ES 2BA	ES 2CA	ES 2DA	ES 2EA	ES 2GA	ES 2HA	ES 2JA	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	2.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	$I_{FSM}$	50								A
Maximum Instantaneous Forward Voltage @ 2.0A	$V_F$	0.95			1.3		1.7			V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage	$I_R$					10				uA
Maximum DC Reverse Current @ $T_A = 100^\circ\text{C}$						350				uA
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$					35				nS
Typical Junction Capacitance ( Note 2 )	$C_j$	25			20					pF
Maximum Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$					75				°C /W
						20				
Operating Temperature Range	$T_J$					-55 to +150				°C
Storage Temperature Range	$T_{STG}$					-55 to +150				°C

- Notes:
1. Reverse Recovery Test Conditions:  $I_F=0.5A$ ,  $I_R=1.0A$ ,  $I_{RR}=0.25A$
  2. Measured at 1 MHz and Applied  $V_R=4.0$  Volts
  3. Units Mounted on P.C.B. 0.2" x 0.2" (5mm x 5mm) Pad Areas

### RATINGS AND CHARACTERISTIC CURVES (ES2AA THRU ES2JA)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

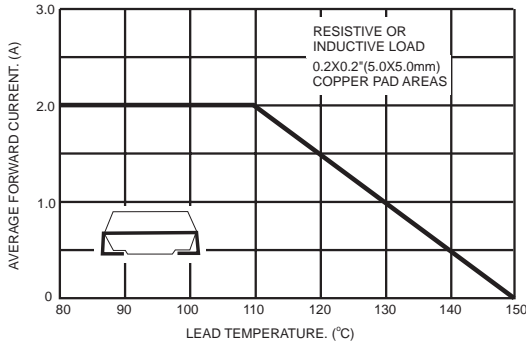


FIG.2- TYPICAL REVERSE CHARACTERISTICS

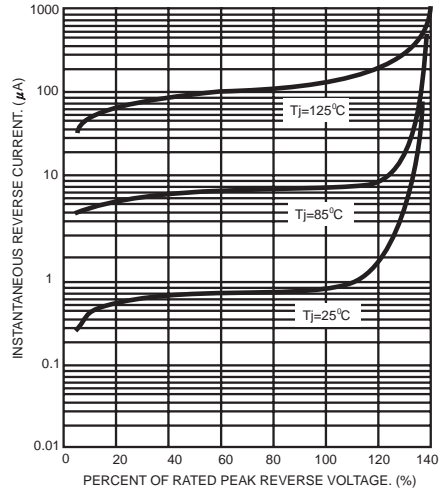


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

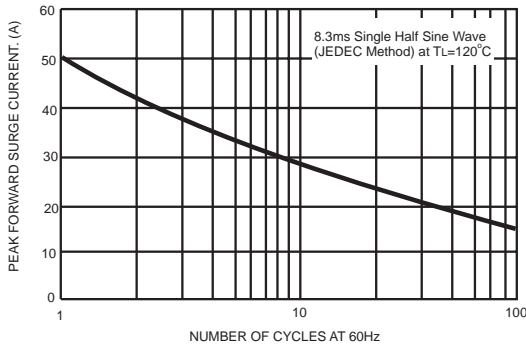


FIG.5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

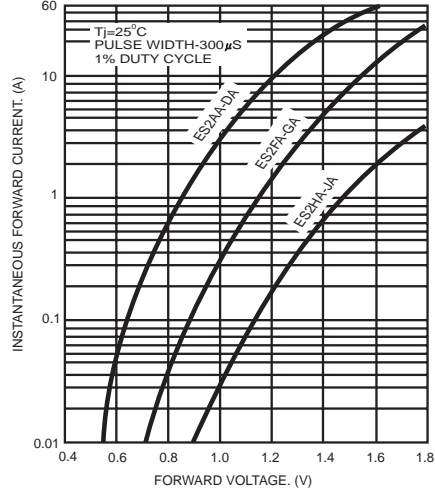


FIG.4- TYPICAL JUNCTION CAPACITANCE

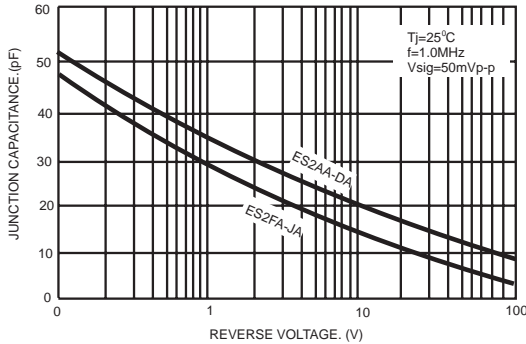
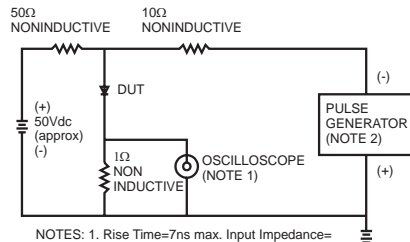


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance=1 megohm 22pf  
2. Rise Time=10ns max. Source Impedance=50 ohms

